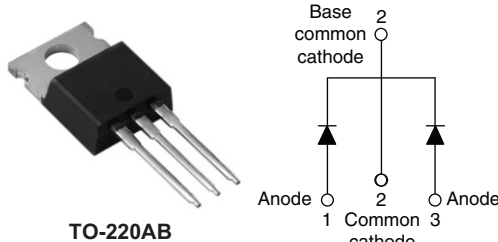


High Performance Schottky Generation 5.0, 2 x 15 A


TO-220AB

FEATURES

- 175 °C high performance Schottky diode
- Very low forward voltage drop
- Extremely low reverse leakage
- Optimized V_F vs. I_F trade off for high efficiency
- Increased ruggedness for reverse avalanche capability
- RBSOA available
- Negligible switching losses
- Submicron trench technology
- Full lead (Pb)-free and RoHS compliant devices
- Designed and qualified for industrial level


RoHS
COMPLIANT

PRODUCT SUMMARY

$I_{F(AV)}$	2 x 15 A
V_R	45 V
V_F at 15 A at 125 °C	0.54 A

APPLICATIONS

- High efficiency SMPS
- Automotive
- High frequency switching
- Output rectification
- Reverse battery protection
- Freewheeling
- Dc-to-dc systems
- Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
V_{RRM}		45	V
V_F	15 Apk, $T_J = 125$ °C (typical, per leg)	0.50	
T_J	Range	- 55 to 175	°C

VOLTAGE RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	30CTT045	UNITS
Maximum DC reverse voltage	V_R	$T_J = 25$ °C	45	V

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current per leg per device	$I_{F(AV)}$	50 % duty cycle at $T_C = 146$ °C, rectangular waveform	15	A
			30	
Maximum peak one cycle non-repetitive surge current per leg	I_{FSM}	5 μ s sine or 3 μ s rect. pulse	880	
		10 ms sine or 6 ms rect. pulse	220	
Non-repetitive avalanche energy per leg	E_{AS}	$T_J = 25$ °C, $I_{AS} = 5$ A, $L = 4.4$ mH	55	mJ
Repetitive avalanche current per leg	I_{AR}	Limited by frequency of operation and time pulse duration so that $T_J < T_J$ max. I_{AS} at T_J max. as a function of time pulse See fig. 8	I_{AS} at T_J max.	A

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward voltage drop per leg	$V_{FM}^{(1)}$	15 A	$T_J = 25\text{ }^{\circ}\text{C}$	-	0.60	V
		30 A		-	0.72	
		15 A	$T_J = 125\text{ }^{\circ}\text{C}$	-	0.54	
		30 A		-	0.69	
Reverse leakage current per leg	$I_{RM}^{(1)}$	$T_J = 25\text{ }^{\circ}\text{C}$	$V_R = \text{Rated } V_R$	-	100	μA
		$T_J = 125\text{ }^{\circ}\text{C}$		-	8	mA
Junction capacitance per leg	C_T	$V_R = 5\text{ V}_{DC}$ (test signal range 100 kHz to 1 MHz) $25\text{ }^{\circ}\text{C}$		1020	-	pF
Series inductance per leg	L_S	Measured lead to lead 5 mm from package body		8.0	-	nH
Maximum voltage rate of change	dV/dt	Rated V_R		-	10 000	V/ μs

Note(1) Pulse width < 300 μs , duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	2.5	°C/W
Maximum thermal resistance, junction to case per device				1.25	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.5	
Approximate weight				2	g
				0.07	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device			Case style TO-220AB	30CTT045	

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Vishay High Power Products

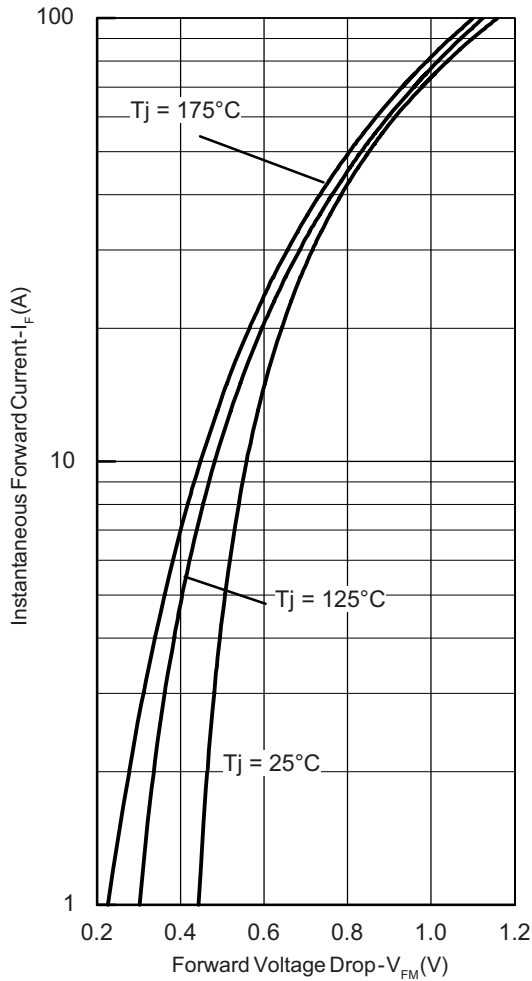


Fig. 1 - Maximum Forward Voltage Drop Characteristics

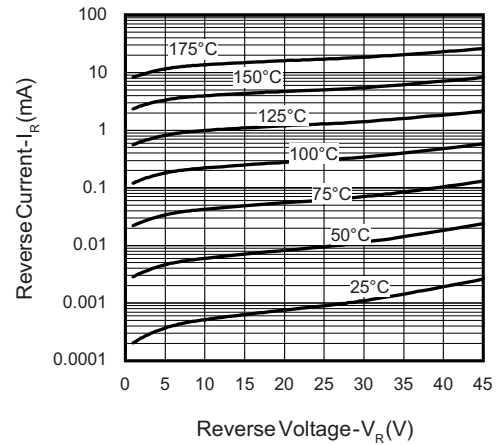


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

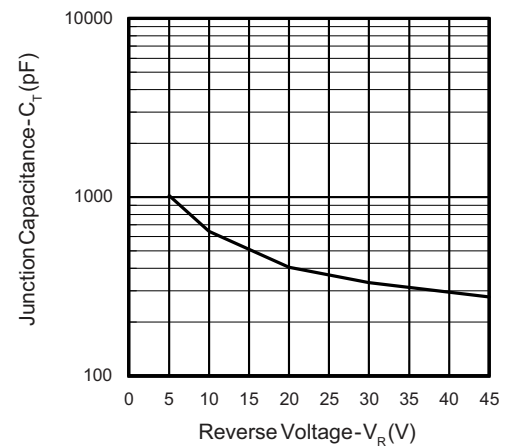


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

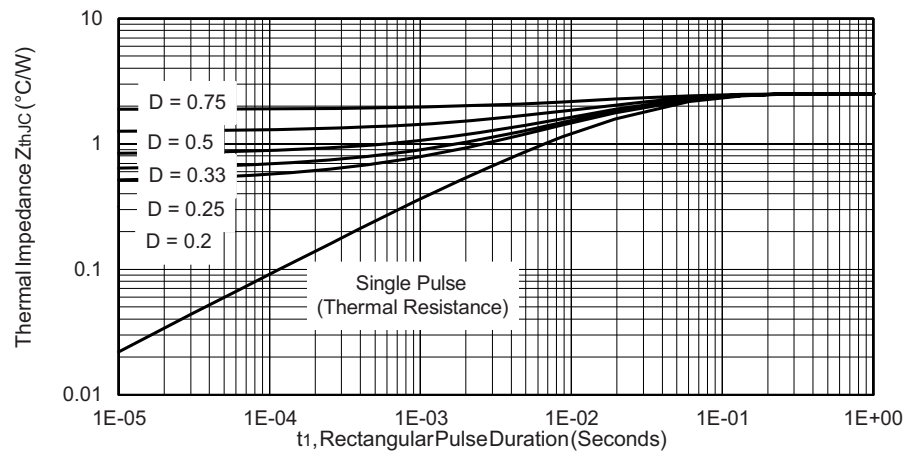


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

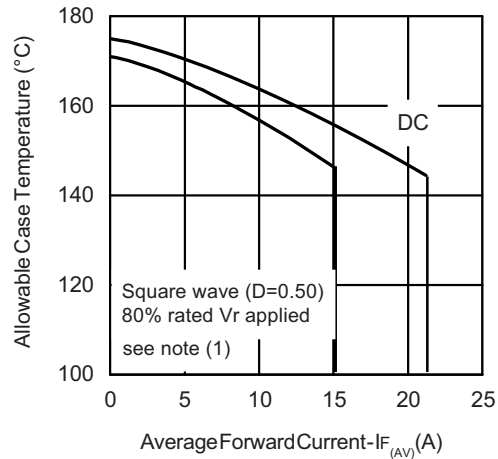


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

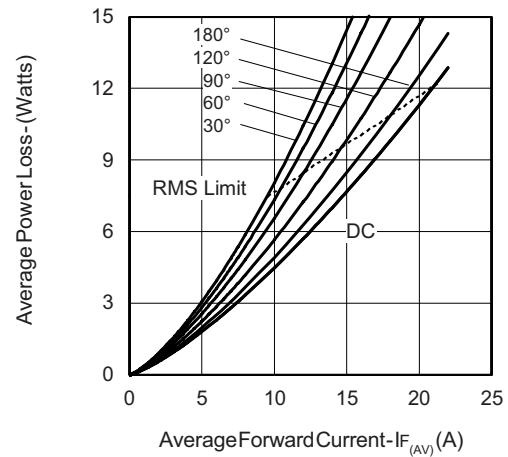


Fig. 6 - Forward Power Loss Characteristics

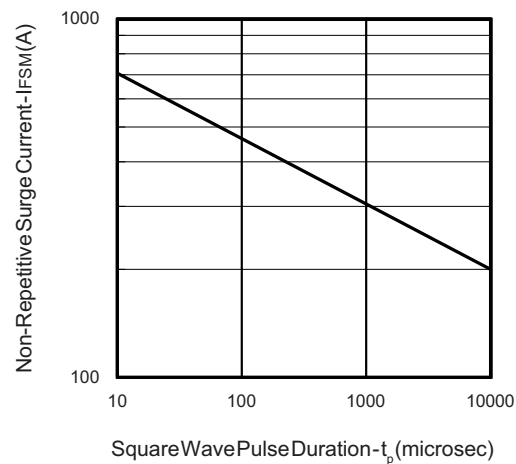


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$
 P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 $P_{d_{REV}}$ = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R

High Performance
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Vishay High Power Products

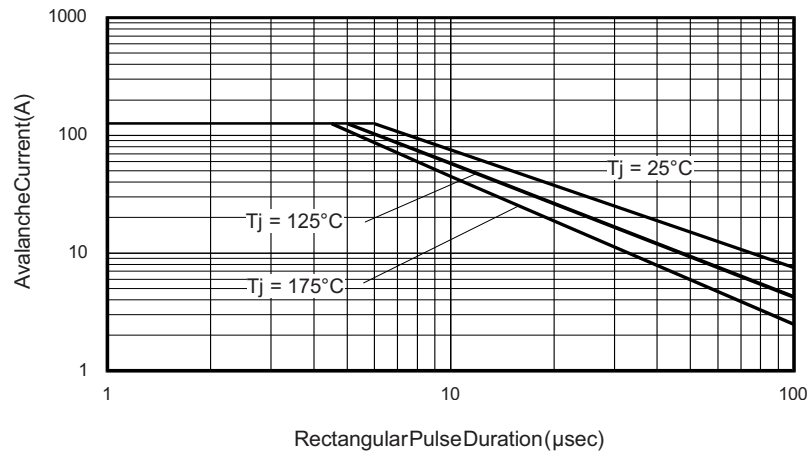


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

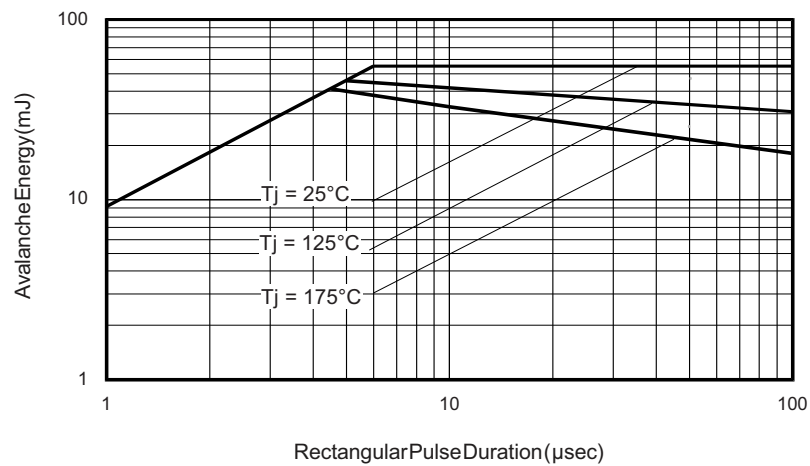


Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)

ORDERING INFORMATION TABLE

Device code	30	C	T	T	045
	①	②	③	④	⑤
	1	-	Current rating (30 A)		
	2	-	Circuit configuration:		
			C = Common cathode		
	3	-	Package:		
			T = TO-220		
	4	-	T = Trench		
	5	-	Voltage code (45 V)		

Tube standard pack quantity: 50 pieces

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95222
Part marking information	http://www.vishay.com/doc?95225



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